

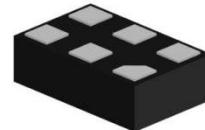
## WS7916DC

### CMOS High Gain GPS LNA

<http://www.sh-willsemi.com>

#### Descriptions

The WS7916DC is a low noise amplifier (LNA) for GNSS receiver applications, available in a small 6-pin DFN package. The WS7916DC requires only one external inductor for input matching.

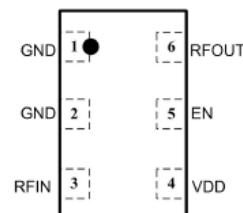


**DFN1510-6L (Bottom view)**

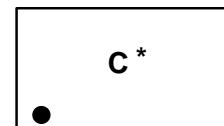
The WS7916DC is designed to achieve low power dissipation and good performance.

#### Features

- Operating frequency: 1550 MHz to 1615 MHz
- Noise figure = 0.60 dB
- Gain = 17.0 dB
- Input 1 dB compression point = -7.0 dBm
- In-band input IP3 = +4.0 dBm
- Supply voltage: 1.8 V to 3.1 V
- Integrated supply decoupling capacitor
- Supply current: 8.0 mA
- Power-down mode leakage current < 10 $\mu$ A
- One external matching inductor required
- Output decoupled to ground
- ESD protection: HBM > 2.0kV for all pins
- Integrated input/output DC block capacitor
- Integrated output matching
- Package: 6-pin DFN, 1.5 x 1.0 x 0.55 mm<sup>3</sup>
- Process: CMOS



**Pin configuration (Top view)**



C = Device code

\* = Month code (A~Z)

**Marking (Top view)**

#### Applications

- Cell phones
- Tablets
- Other RF front-end modules

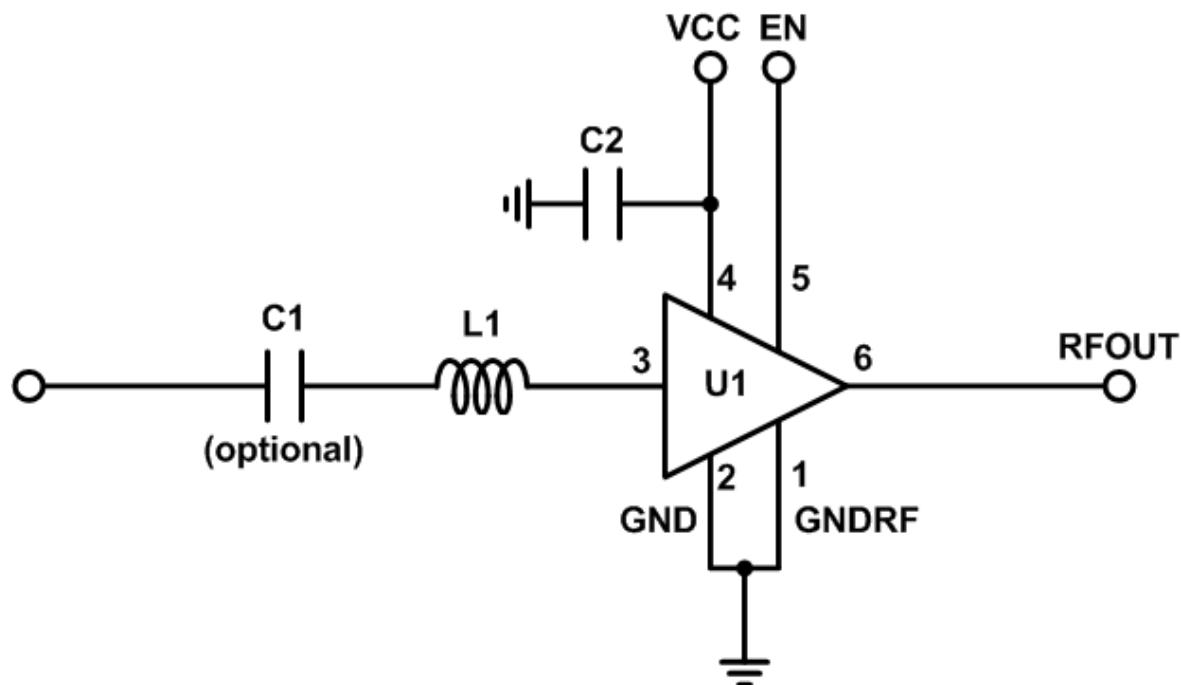
#### Order information

Device	Package	Shipping
WS7916DC-6/TR	DFN1510-6L	3000/Reel&Tape

## Pinning Information

Pin	Description	Transparent top view	Symbol view
1	GNDRF		
2	GND		
3	RFIN		
4	VDD		
5	EN		
6	RFOUT		

## Application Information



Symbol	Description	Footprint	Value	Supplier	Comment
U1	WS7916DC	1.5x1.0x0.55 mm <sup>3</sup>	NA	Will-Semi	DUT
C1	Capacitor	0402	1 nF	Various	DC blocking
C2	Capacitor	0402	1 nF	Various	Supply decoupling
L1	Inductor	0402	10 nH	Murata LQW15	Input matching

## Quick Reference Data

Freq = 1575.42 MHz;  $V_{CC}$  = 2.8 V;  $V_{EN} > 1.2$  V; Temp = 25°C; input matched to 50 Ω with a 10 nH inductor. The condition is applied unless otherwise specified.

Symbol	Parameter	Condition	Min	Typ	Max	Unit
$V_{CC}$	Supply voltage		1.6	2.8	3.1	V
$I_{CC}$	Supply current			8.0		mA
$G_p$	Power gain			17.0		dB
NF	Noise figure			0.60		dB
$IP_{1dB}$	Input power at 1dB gain compression			-7.0		dBm
$IIP_3$	Input third-order intercept point			+4.0		dBm

## Recommended Operating Conditions

Symbol	Parameter	Condition	Min	Typ	Max	Unit
$V_{CC}$	Supply voltage		1.6	2.8	3.1	V
Temp	Ambient temperature		-40	+25	+85	°C
$V_{EN}$	Input voltage on pin 6 (EN)	OFF state	0		0.3	V
		ON state	1.2		$V_{CC}$	V

## Absolute Maximum Ratings

Maximum ratings are absolute ratings, exceeding only one of these values may cause irreversible damage to the integrated circuit.

Symbol	Parameter	Condition	Min	Max	Unit
$V_{CC}$	Supply voltage		-0.3	3.3	V
$V_{EN}$	Input voltage on pin EN		-0.3	3.3	V
$V_{RFIN}$	Input voltage on pin RFIN		-0.3	3.3	V
$V_{RFOUT}$	Input voltage on pin RFOUT		-0.3	3.3	V
$P_{in}$	RF input power			0	dBm
$T_{STG}$	Storage temperature		-65	+150	°C
$T_J$	Junction temperature			150	°C
$V_{ESD}$	ESD capability all pins	Human Body Model (HBM)		±2000	V

## Characteristics

$1550 \text{ MHz} \leq f \leq 1615 \text{ MHz}$ ;  $V_{CC} = 2.8 \text{ V}$ ;  $V_{EN} > 1.2 \text{ V}$ ; Temp =  $25^\circ\text{C}$ ; input mated to  $50 \Omega$  with a  $10 \text{ nH}$  inductor; The condition is applied unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$I_{CC}$	Supply current	On state		8.0		mA
		Off state		8.5	10	$\mu\text{A}$
$G_p$	Power gain	$f = 1575 \text{ MHz}$		17.0		dB
$RL_{in}$	Input return loss	$f = 1575 \text{ MHz}$		6.0		dB
$RL_{out}$	Output return loss	$f = 1575 \text{ MHz}$		18.0		dB
ISL	Reverse isolation	$f = 1575 \text{ MHz}$		26.0		dB
NF	Noise figure	$f = 1575 \text{ MHz}$		0.60		dB
$IP_{1\text{dB}}$	Input power at 1 dB gain compression	$f = 1575 \text{ MHz}$		-7.0		dBm
$IIP_3$	Input third-order intercept point <sup>[1]</sup>			+4.0		dBm
K	Rollett stability factor <sup>[2]</sup>		1			
$t_{on}$	Turn-on time				5	$\mu\text{s}$
$t_{off}$	Turn-off time				5	$\mu\text{s}$

[1]  $f_1 = 1713 \text{ MHz}$ ,  $f_2 = 1851 \text{ MHz}$ ,  $P_{in} = -20 \text{ dBm}$

[2] 10M~20GHz

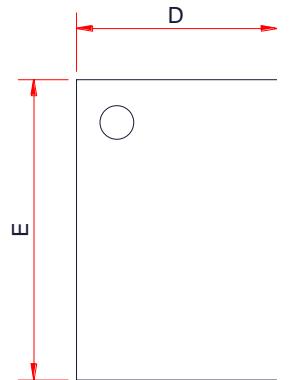
## Characteristics

$1550 \text{ MHz} \leq f \leq 1615 \text{ MHz}$ ;  $V_{CC} = 1.8 \text{ V}$ ;  $V_{EN} > 1.2 \text{ V}$ ; Temp =  $25^\circ\text{C}$ ; input mated to  $50 \Omega$  with a  $10 \text{ nH}$  inductor; The condition is applied unless otherwise specified.

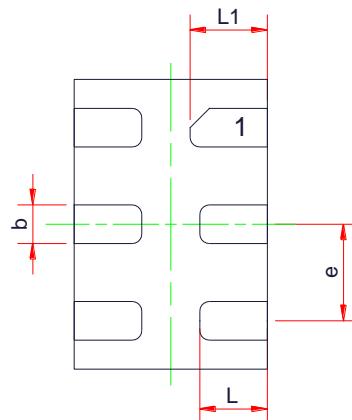
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$I_{CC}$	Supply current	On state		8.2		mA
		Off state		4.5	5.5	$\mu\text{A}$
$G_p$	Power gain	$f = 1575 \text{ MHz}$		17.0		dB
$RL_{in}$	Input return loss	$f = 1575 \text{ MHz}$		5.8		dB
$RL_{out}$	Output return loss	$f = 1575 \text{ MHz}$		18.5		dB
ISL	Reverse isolation	$f = 1575 \text{ MHz}$		25.5		dB
NF	Noise figure	$f = 1575 \text{ MHz}$		0.60		dB
$IP_{1\text{dB}}$	Input power at 1 dB gain compression	$f = 1575 \text{ MHz}$		-10.0		dBm
$IIP_3$	Input third-order intercept point <sup>[1]</sup>			+3.5		dBm
K	Rollett stability factor <sup>[2]</sup>		1			
$t_{on}$	Turn-on time				5	$\mu\text{s}$
$t_{off}$	Turn-off time				5	$\mu\text{s}$

[1]  $f_1 = 1713 \text{ MHz}$ ,  $f_2 = 1851 \text{ MHz}$ ,  $P_{in} = -20 \text{ dBm}$

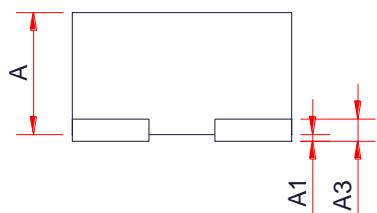
[2] 10M~20GHz

**Package Outline dimensions**
**DFN1510-6L**


TOP VIEW

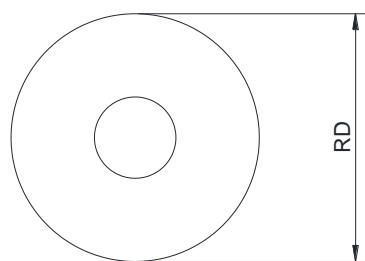
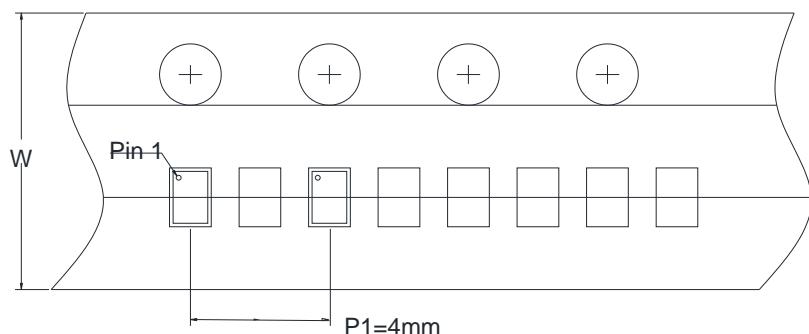


BOTTOM VIEW

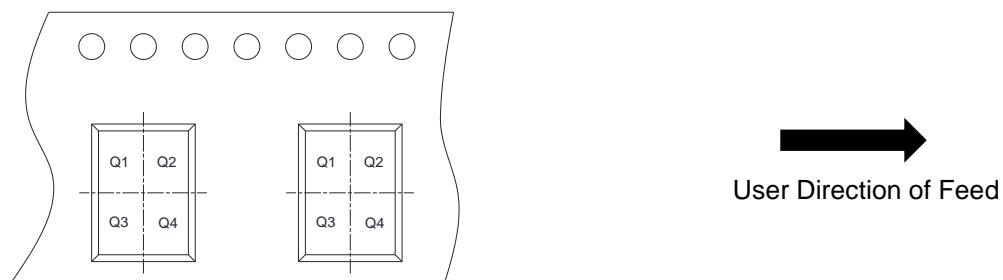


SIDE VIEW

Symbol	Dimensions in Millimeters		
	Min.	Typ.	Max.
A	0.50	0.55	0.60
A1	0.00	-	0.05
A3	0.13Ref		
D	0.90	1.00	1.10
E	1.40	1.50	1.60
b	0.15	0.20	0.25
e	0.40	0.50	0.50
L	0.27	-	0.42
L1	0.32	-	0.48

**TAPE AND REEL INFORMATION**
**Reel Dimensions**

**Tape Dimensions**


**Note:** Tape material is plastic. Pitch between successive cavity centers is 2mm.

**Quadrant Assignments For PIN1 Orientation In Tape**


RD	Reel Dimension	<input checked="" type="checkbox"/> 7inch <input type="checkbox"/> 13inch
W	Overall width of the carrier tape	<input checked="" type="checkbox"/> 8mm <input type="checkbox"/> 12mm <input type="checkbox"/> 16mm
P1	Pitch between successive chip centers	<input type="checkbox"/> 2mm <input checked="" type="checkbox"/> 4mm <input type="checkbox"/> 8mm
Pin1	Pin1 Quadrant	<input checked="" type="checkbox"/> Q1 <input type="checkbox"/> Q2 <input type="checkbox"/> Q3 <input type="checkbox"/> Q4

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